**TECHNICAL DATA, Rev-**

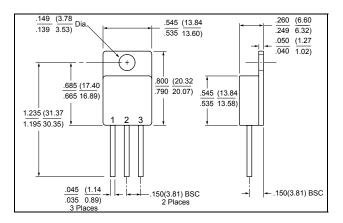
# HERMETIC POWER SCHOTTKY RECTIFIER

### **Applications:**

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

### Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Includes 100% screening, Group A and Group B testing on the finished part in accordance with MIL-PRF-19500 for TX level parts. JAN and TXV level also available



#### Mechanical Dimensions: In Inches / mm

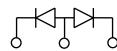
<u>TO-254</u>

### PINOUT TABLE

ТҮРЕ	PIN 1	PIN 2	PIN 3
DUAL RECTIFIER, COMMON CATHODE	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER, COMMON ANODE (R)	CATHODE 1	COMMON ANODE	CATHODE 2

### SCHEMATIC

**COMMON CATHODE** 



**COMMON ANODE** 

### **TECHNICAL DATA, Rev-**

### Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	45	V
Max. Average Forward Current (Total Package) *	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =100°C, rectangular wave form	30	A
Max. Peak One Cycle Non- Repetitive Surge Current (Per Leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	300	A
Non-Repetitive Avalanche Energy (Per Leg)	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 2.0 A, L = 0.26 mH	0.54	mJ

\* Derate linearly at 300 mA/ °C from  $T_J = T_C = +100$  °C to +150 °C. 300 mA /°C times 50 °C = 15 A, the device rating.

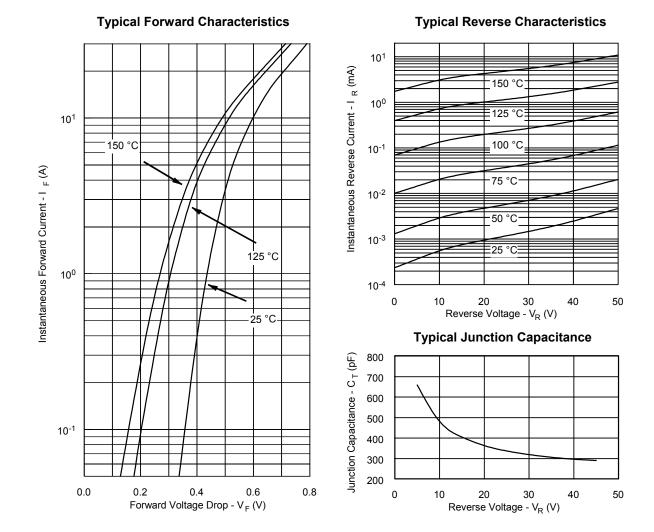
### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V <sub>F1</sub>	@ 5 A, Pulse, T <sub>J</sub> = 25 °C	0.55	V
(Per Leg)	V <sub>F2</sub>	@ 15 A, Pulse, T <sub>J</sub> = 25 °C	0.75	
	V <sub>F3</sub>	@ 30 A, Pulse, T <sub>J</sub> = 25 °C	1.00	
	V <sub>F4</sub>	@ 15 A, Pulse, T <sub>J</sub> = -55 °C	0.80	V
Max. Reverse Current	I <sub>R1</sub>	@V <sub>R</sub> = 45 V, Pulse,	1.0	mA
(Per Leg)		T <sub>J</sub> = 25 °C		
	I <sub>R2</sub>	@V <sub>R</sub> = 45V, Pulse,	40	mA
		T <sub>J</sub> = 125 °C		
Max. Junction Capacitance	CT	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C	2000	pF
(Per Leg)		f <sub>SIG</sub> = 1MHz,		
		V <sub>SIG</sub> = 50mV (p-p)		
Max. Voltage Rate of	dv/dt	-	10,000	V/μs
Change (Per Leg)				

### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	TJ	-	-65 to +150	Ο°
Max. Storage Temperature	T <sub>stg</sub>	-	-65 to +150	Ο°
Maximum Thermal Resistance Junction to Case (Per Leg)	$R_{ extsf{ heta}JC}$	DC operation	1.65	°C/W
Case Style	Hermetic TO-254			

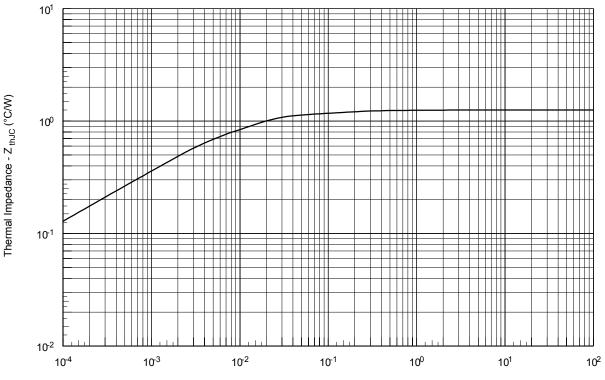
### **TECHNICAL DATA, Rev-**



• 221 West Industry Court I Deer Park, NY 11729-4681 II (631) 586-7600 FAX (631) 242-9798 •

World Wide Web Site - http://www.sensitron.com • E-Mail Address - sales@sensitron.com •

#### **TECHNICAL DATA, Rev-**



**Typical Thermal Resistance** 

Single Rectangular Pulse Duration (sec)

#### DISCLAIMER:

1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the Sensitron Semiconductor sales department for the latest version of the datasheet(s).

2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.

3- In no event shall Sensitron Semiconductor be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). Sensitron Semiconductor assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.

4- In no event shall Sensitron Semiconductor be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.

5- No license is granted by the datasheet(s) under any patents or other rights of any third party or Sensitron Semiconductor.

6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of Sensitron Semiconductor.

7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations.

• 221 West Industry Court ☐ Deer Park, NY 11729-4681 ☐ (631) 586-7600 FAX (631) 242-9798 •

World Wide Web Site - http://www.sensitron.com • E-Mail Address - sales@sensitron.com •